FAIRCHILD SEMICONDUCTOR®

February 2010

MCT6, MCT61, MCT62
Dual Phototransistor Optocouplers

Features

- Two isolated channels per package
- Two packages fit into a 16 lead DIP socket
- Choice of three current transfer ratios
- Underwriters Laboratory (U.L.) recognized File E90700
- VDE approved for IEC60747-5-2

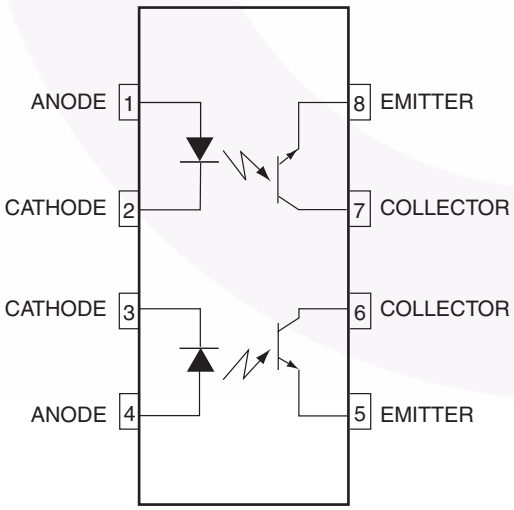
Applications

- AC line/digital logic – isolate high voltage transients
- Digital logic/digital logic – eliminate spurious grounds
- Digital logic/AC triac control – isolate high voltage transients
- Twisted pair line receiver – eliminate ground loop feedthrough
- Telephone/telegraph line receiver – isolate high voltage transients
- High frequency power supply feedback control – maintain floating grounds and transients
- Relay contact monitor – isolate floating grounds and transients
- Power supply monitor – isolate transients

Description

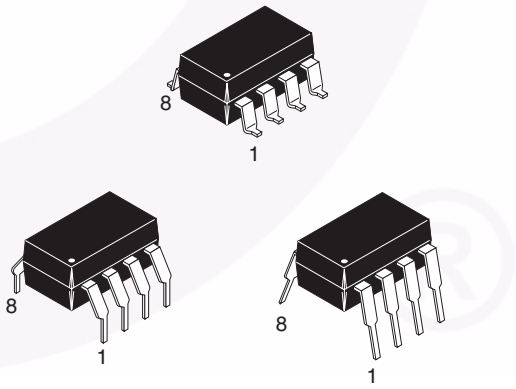
The MCT6X Optocouplers have two channels for density applications. For four channel applications, two-packages fit into a standard 16-pin DIP socket. Each channel is an NPN silicon planar phototransistor optically coupled to a gallium arsenide infrared emitting diode.

Schematic



Equivalent Circuit

Package Outlines



Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Rating	Value	Unit
TOTAL DEVICE			
T_{STG}	Storage Temperature	-55 to +150	°C
T_{OPR}	Operating Temperature	-55 to +100	°C
T_{SOL}	Lead Solder Temperature (Refer to Reflow Temperature Profile)	260 for 10 sec	°C
P_D	Total Device Power Dissipation @ T_A = 25°C	400	mW
	Derate above 25°C	5.33	mW/°C
EMITTER (Each channel)			
I_F	Forward Current – Continuous	60	mA
I_F(pk)	Forward Current – Peak (PW = 1µs, 300pps)	3	A
V_R	Reverse Voltage	3.0	V
P_D	LED Power Dissipation @ T_A = 25°C	100	mW
	Derate above 25°C (Total Input)	1.3	mW/°C
DETECTOR (Each channel)			
I_C	Collector Current – Continuous	30	mA
P_D	Detector Power Dissipation @ T_A = 25°C	150	mW
	Derate above 25°C	2.0	mW/°C

Electrical Characteristics (T_A = 25°C unless otherwise specified)

Individual Component Characteristics

Symbol	Parameter	Test Conditions	Min.	Typ.*	Max.	Units
EMITTER						
V_F	Input Forward Voltage	I_F = 20mA		1.2	1.5	V
V_R	Reverse Voltage	I_R = 10µA	3.0	25		V
I_R	Reverse Current	V_R = 5V		0.001	10	µA
C_J	Junction Capacitance	V_F = 0V, f = 1MHz		50		pF
DETECTOR						
BV_{CEO}	Collector-Emitter Breakdown Voltage	I_C = 1.0mA, I_F = 0	30	85		V
BV_{ECO}	Emitter-Collector Breakdown Voltage	I_E = 100µA, I_F = 0	6	13		V
I_{CEO}	Collector-Emitter Dark Current	V_{CE} = 10V, I_F = 0		5	100	nA
C_{CE}	Capacitance	V_{CE} = 0V, f = 1MHz		8		pF

Transfer Characteristics

Symbol	Characteristic	Test Conditions	Min.	Typ.*	Max.	Units
SWITCHING CHARACTERISTICS (AC)						
t_{on}	Non-Saturated Turn-on Time	R_L = 100Ω, I_C = 2mA, V_{CC} = 10V		2.4		µs
t_{off}	Non-Saturated Turn-off Time			2.4		µs
CURRENT TRANSFER RATIO, COLLECTOR-EMITTER (DC)						
CTR	MCT6	I_F = 10mA, V_{CE} = 10V	20			%
	MCT61	I_F = 5mA, V_{CE} = 5V	50			
	MCT62		100			
$V_{CE(sat)}$	Saturation Voltage	I_F = 16mA, I_C = 2mA		0.15	0.40	V

Isolation Characteristics

Symbol	Characteristic	Test Conditions	Min.	Typ.*	Max.	Units
V_{ISO}	Input-Output Isolation Voltage	$I_{I-O} \leq$ 10µA, t = 1min.	5000			Vac(rms)
R_{ISO}	Isolation Resistance	V_{I-O} = 500VDC	10^{11}			Ω
C_{ISO}	Isolation Capacitance	f = 1MHz		0.5		pF

*All typicals at T_A = 25°C

Typical Performance Curves

Fig. 1 Normalized CTR vs. Forward Current

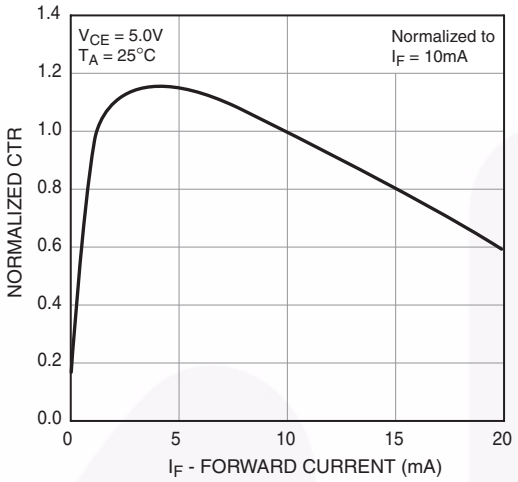


Fig. 2 Normalized CTR vs. Ambient Temperature

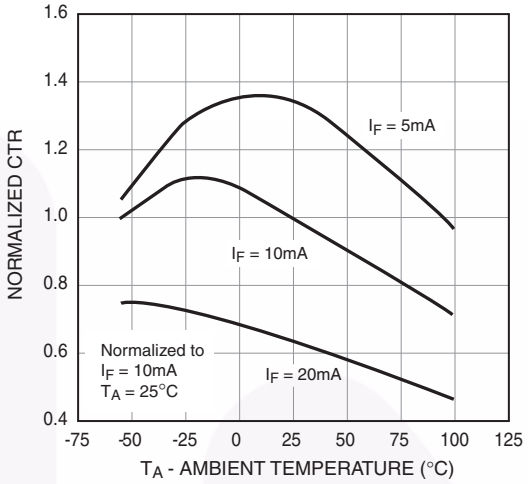


Fig. 3 Dark Current vs. Ambient Temperature

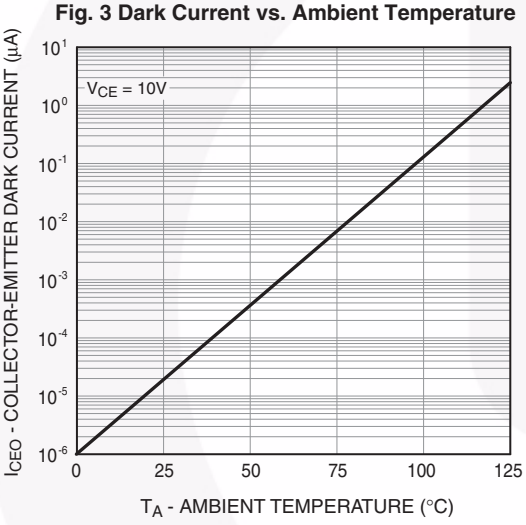


Fig. 4 Switching Speed vs. Load Resistor

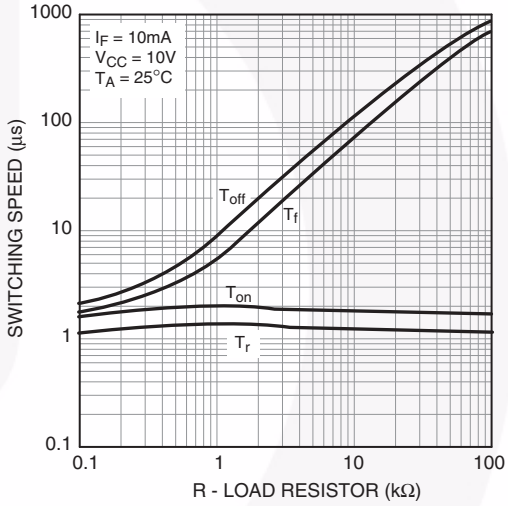


Fig. 5 LED Forward Voltage vs. Forward Current

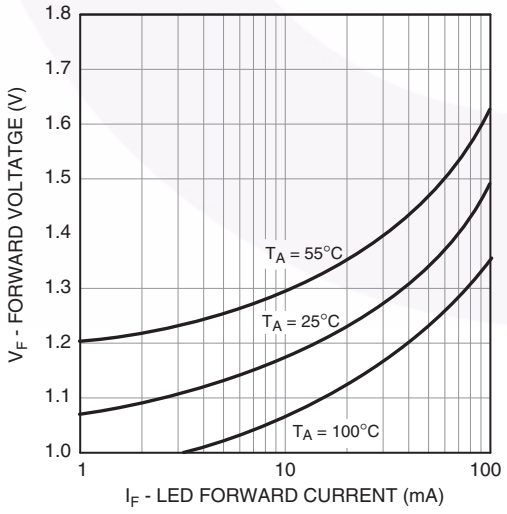
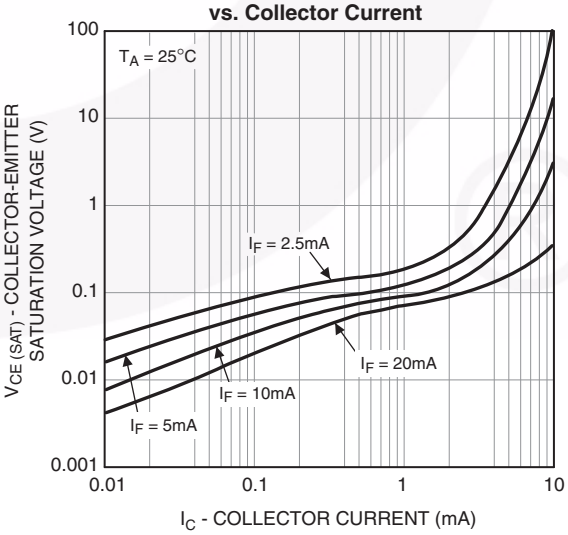
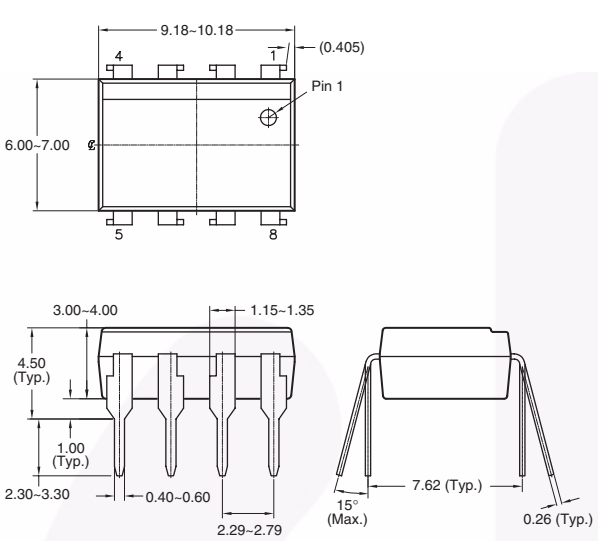


Fig. 6 Collector-Emitter Saturation Voltage vs. Collector Current

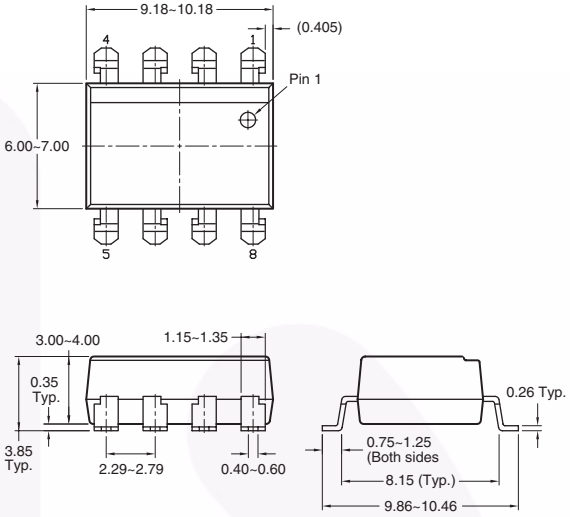


Package Dimensions

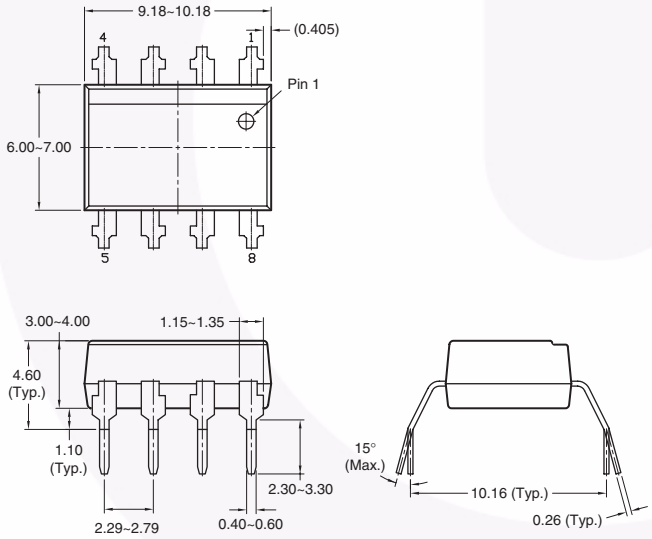
Through Hole



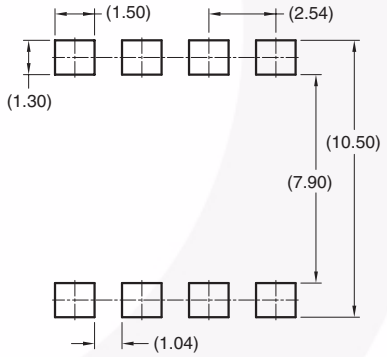
Surface Mount



0.4" Lead Spacing



Recommend Pad Layout for Surface Mount Leadform

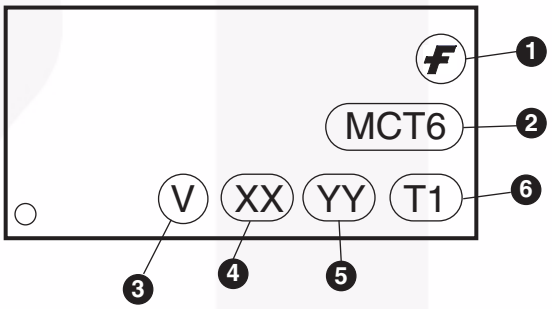


Note:
All dimensions are in millimeters.

Ordering Information

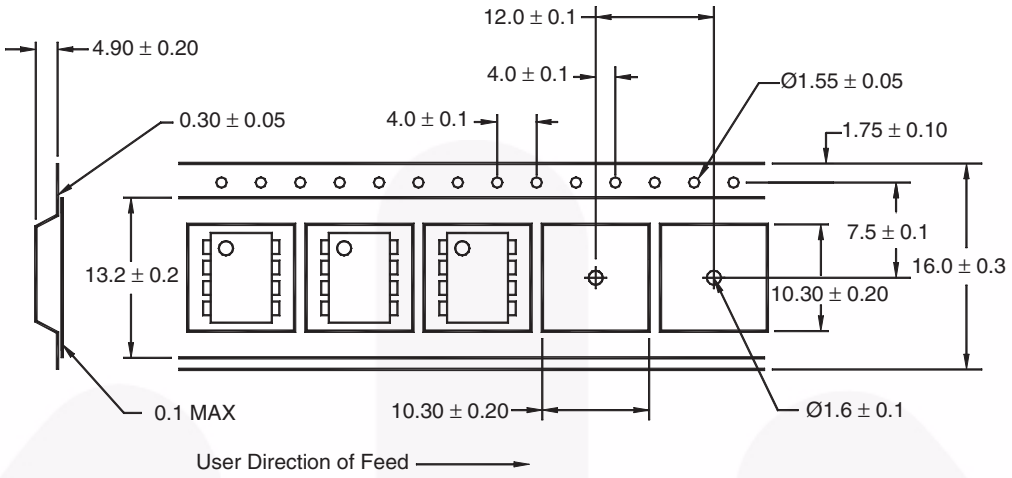
Option	Example Part Number	Description
No Option	MTC6	Standard Through Hole
S	MTC6S	Surface Mount Lead Bend
SD	MTC6SD	Surface Mount; Tape and Reel
300	MCT6300	VDE Approved
3S	MCT63S	Surface Mount Lead Bend; VDE Approved
3SD	MCT63SD	Surface Mount; Tape and Reel; VDE Approved
300W	MTC6300W	0.4" Lead Spacing; VDE Approved

Marking Information



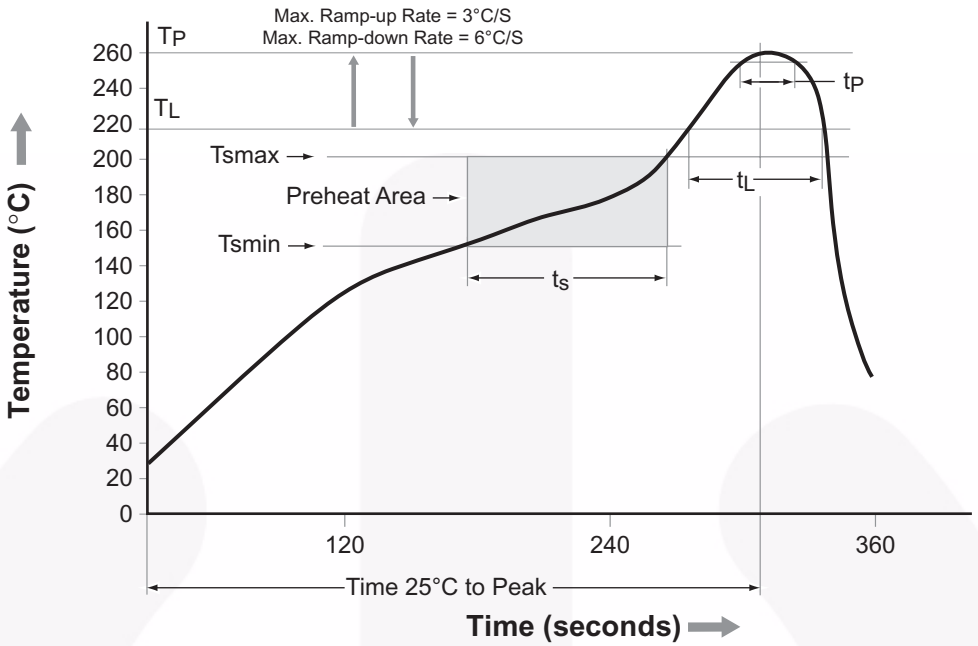
Definitions	
1	Fairchild logo
2	Device number
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)
4	Two digit year code, e.g., ‘03’
5	Two digit work week ranging from ‘01’ to ‘53’
6	Assembly package code

Carrier Tape Specifications



Note:
All dimensions are in inches (millimeters)

Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (t_S) from (Tsmin to Tsmax)	60–120 seconds
Ramp-up Rate (t_L to t_P)	3°C/second max.
Liquidous Temperature (T_L)	217°C
Time (t_L) Maintained Above (T_L)	60–150 seconds
Peak Body Package Temperature	260°C +0°C / –5°C
Time (t_P) within 5°C of 260°C	30 seconds
Ramp-down Rate (T_P to T_L)	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.

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Definition of Terms

Datasheet Identification	Product Status	Definition
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Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
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